Conformal Growth of Nanocrystalline CdX (X=S, Se) on Mesoscopic NiO and Their Photoelectrochemical Properties

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Figure S1. TEM and HRTEM images of CdS-coated NiO nano-particles after 10 SILAR

deposition cycles.

CdS/CdSe	$V_{oc} (\mathrm{mV})$	j_{sc} (mA cm ⁻²)	FF (%)	j_{sc} obtained from
				IPCE (mA cm ⁻²) ^a
10/0	58	0.16	20.8	0.35
0/10	66	0.63	31.7	1.29
5/5	66	0.71	29.3	2.12
3/10	86	0.87	32.3	2.22

Table S1. Comparison of photovoltaic parameters of CdS, CdSe and CdS/CdSe cells under simulated AM 1.5, 100 mW cm⁻² illumination.

^a Calculated by integrating IPCE over AM1.5 solar irradiance.

Table S2. Comparison of photovoltaic parameters of CdSe and CdS/CdSe cells under 1 Sun and

0.1 Sun illumination intensities.

Light intensity	Sensitizer	Voc (mV)	j_{sc} (mA cm ⁻²)	FF (%)	Efficiency
1 Sun	CdSe	66	0.63	31	0.014
0.1 Sun	CdSe	32	0.24	30	0.023
1 Sun	CdS/CdSe	86	0.87	32	0.02
0.1 Sun	CdS/CdSe	40	0.45	27	0.05



Figure S2. Cell performance comparison for different cascade structures.



Figure S3. Injection efficiency vs. wavelength calculated for a 10 CdSe/NiO cell.